

# **LM56 Dual Output Low Power Thermostat**

Check for Samples: LM56

#### **FEATURES**

- Digital Outputs Support TTL Logic Levels
- Internal Temperature Sensor
- 2 Internal Comparators with Hysteresis
- Internal Voltage Reference
- Available in 8-pin SOIC and VSSOP Packages

#### **APPLICATIONS**

- Microprocessor Thermal Management
- Appliances
- Portable Battery Powered 3.0V or 5V Systems
- Fan Control
- Industrial Process Control
- HVAC Systems
- Remote Temperature Sensing
- Electronic System Protection

#### **DESCRIPTION**

The LM56 is a precision low power thermostat. Two stable temperature trip points (V $_{T1}$  and V $_{T2}$ ) are generated by dividing down the LM56 1.250V bandgap voltage reference using 3 external resistors. The LM56 has two digital outputs. OUT1 goes LOW when the temperature exceeds T1 and goes HIGH when the temperature goes below (T1-T $_{HYST}$ ). Similarly, OUT2 goes LOW when the temperature exceeds T2 and goes HIGH when the temperature goes below (T2-T $_{HYST}$ ). T $_{HYST}$  is an internally set 5°C typical hysteresis.

The LM56 is available in an 8-lead VSSOP surface mount package and an 8-lead SOIC.

Table 1. Key Specifications

|  | VALUE                         | UNIT        |
|--|-------------------------------|-------------|
| Power Supply Voltage                       | 2.7V-10                       | V           |
| Power Supply Current                       | 230                           | μA (max)    |
| V <sub>REF</sub>                           | 1.250                         | V ±1% (max) |
| Hysteresis Temperature                     | 5                             | °C          |
| Internal Temperature Sensor Output Voltage | (+6.20 mV/°C x T) +<br>395 mV | mV          |

**Table 2. Temperature Trip Point Accuracy** 

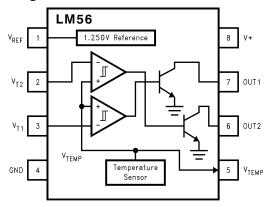
|                 | LM56BIM    | LM56CIM    |
|-----------------|------------|------------|
| +25°C           | ±2°C (max) | ±3°C (max) |
| +25°C to +85°C  | ±2°C (max) | ±3°C (max) |
| -40°C to +125°C | ±3°C (max) | ±4°C (max) |

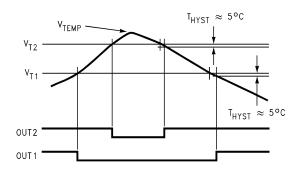
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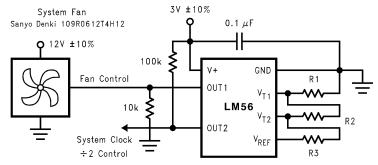
## Simplified Block Diagram and Connection Diagram

#### **Block Diagram**





## **Typical Application**



 $\begin{array}{l} V_{T1} = 1.250 V \; x \; (R1)/(R1+R2+R3) \\ V_{T2} = 1.250 V \; x \; (R1+R2)/(R1+R2+R3) \\ \text{where:} \\ (R1+R2+R3) = 27 \; k\Omega \; \text{and} \\ V_{T1 \; \text{or} \; T2} = [6.20 \; \text{mV/°C} \; x \; T] + 395 \; \text{mV} \; \text{therefore:} \\ R1 = V_{T1}/(1.25 V) \; x \; 27 \; k\Omega \\ R2 = (V_{T2}/(1.25 V) \; x \; 27 \; k\Omega) - R1 \\ R3 = 27 \; k\Omega - R1 - R2 \end{array}$ 

Figure 1. Microprocessor Thermal Management



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.



## Absolute Maximum Ratings(1)

| Input Voltage   | Input Voltage                 |                  |  |  |  |  |  |  |
|---|-------------------------------|------------------|--|--|--|--|--|--|
| Input Current at any pin (2)                                | 5 mA                          |                  |  |  |  |  |  |  |
| Package Input Current <sup>(2)</sup>                        | 20 mA                         |                  |  |  |  |  |  |  |
| Package Dissipation at T <sub>A</sub> = 25°C <sup>(3)</sup> | 900 mW                        |                  |  |  |  |  |  |  |
|   | Human Body Model - Pin 3 Only | 800V             |  |  |  |  |  |  |
| ESD Susceptibility <sup>(4)</sup>                           | All other pins                | 1000V            |  |  |  |  |  |  |
| ESD Susceptibility (7)                                      | Machine Model                 | 125V             |  |  |  |  |  |  |
|   | Storage Temperature           | −65°C to + 150°C |  |  |  |  |  |  |

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the LM56 Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (2) When the input voltage (V<sub>I</sub>) at any pin exceeds the power supply (V<sub>I</sub> < GND or V<sub>I</sub> > V<sup>+</sup>), the current at that pin should be limited to 5 mA. The 20 mA maximum package input current rating limits the number of pins that can safely exceed the power supplies with an input current of 5 mA to four.
- (3) The maximum power dissipation must be derated at elevated temperatures and is dictated by T<sub>Jmax</sub> (maximum junction temperature), θ<sub>JA</sub> (junction to ambient thermal resistance) and T<sub>A</sub> (ambient temperature). The maximum allowable power dissipation at any temperature is P<sub>D</sub> = (T<sub>Jmax</sub>-T<sub>A</sub>)/θ<sub>JA</sub> or the number given in the Absolute Maximum Ratings, whichever is lower. For this device, T<sub>Jmax</sub> = 125°C. For this device the typical thermal resistance (θ<sub>JA</sub>) of the different package types when board mounted follow:
- (4) The human body model is a 100 pF capacitor discharge through a 1.5 kΩ resistor into each pin. The machine model is a 200 pF capacitor discharged directly into each pin.

## Operating Ratings (1)(2)(3)

| Operating Temperature Range               | $T_{MIN} \le T_A \le T_{MAX}$   |
|---|---------------------------------|
| LM56BIM, LM56CIM                          | -40°C ≤ T <sub>A</sub> ≤ +125°C |
| Positive Supply Voltage (V <sup>+</sup> ) | +2.7V to +10V                   |
| Maximum $V_{OUT1}$ and $V_{OUT2}$         | +10V                            |

- (1) Absolute Maximum Ratings indicate limits beyond which damage to the device may occur. Operating Ratings indicate conditions for which the device is functional, but do not guarantee specific performance limits. For guaranteed specifications and test conditions, see the LM56 Electrical Characteristics. The guaranteed specifications apply only for the test conditions listed. Some performance characteristics may degrade when the device is not operated under the listed test conditions.
- (2) Soldering process must comply with Reflow Temperature Profile specifications. Refer to http://www.ti.com/packaging.
- (3) Reflow temperature profiles are different for lead-free and non-lead-free packages.

| Package Type | $\theta_{JA}$ |
|--------------|---------------|
| D0008A       | 110°C/W       |
| DGK0008A     | 250°C/W       |



#### **LM56 Electrical Characteristics**

The following specifications apply for  $V^+ = 2.7 \ V_{DC}$ , and  $V_{REF}$  load current = 50  $\mu A$  unless otherwise specified. **Boldface limits apply for T**<sub>A</sub> = **T**<sub>J</sub> = **T**<sub>MIN</sub> **to T**<sub>MAX</sub>; all other limits T<sub>A</sub> = T<sub>J</sub> = 25°C unless otherwise specified.

| Symbol  | Parameter  | Conditions  | Typical <sup>(1)</sup> | LM56BIM<br>Limits <sup>(2)</sup> | LM56CIM<br>Limits <sup>(2)</sup> | Units (Limits) |
|---|--|---|------------------------|----------------------------------|----------------------------------|----------------|
| Temperatur                                      | e Sensor   | -   | <u> </u>               | 1                                |                                  | I.             |
|   | Trip Point Accuracy (Includes V <sub>REF</sub> ,       |   |                        | ±2                               | ±3                               | °C (max)       |
|   | Comparator Offset, and Temperature Sensitivity errors) | $+25$ °C $\leq T_A \leq +85$ °C   |                        | ±2                               | ±3                               | °C (max)       |
|   | Constitute energy                                      | $-40$ °C $\leq T_A \leq +125$ °C  |                        | ±3                               | ±4                               | °C (max)       |
|   | Trip Point Hysteresis                                  | T <sub>A</sub> = -40°C  | 4                      | 3                                | 3                                | °C (min)       |
|   |  |   |                        | 6                                | 6                                | °C (max)       |
|   |  | T <sub>A</sub> = +25°C  | 5                      | 3.5                              | 3.5                              | °C (min)       |
|   |  |   |                        | 6.5                              | 6.5                              | °C (max)       |
|   |  | T <sub>A</sub> = +85°C  | 6                      | 4.5                              | 4.5                              | °C (min)       |
|   |  |   |                        | 7.5                              | 7.5                              | °C (max)       |
|   |  | T <sub>A</sub> = +125°C   | 6                      | 4                                | 4                                | °C (min)       |
|   |  |   |                        | 8                                | 8                                | °C (max)       |
|   | Internal Temperature Sensitivity                       |   | +6.20                  |                                  |                                  | mV/°C          |
|   | Temperature Sensitivity Error                          |   |                        | ±2                               | ±3                               | °C (max)       |
|   |  |   |                        | ±3                               | ±4                               | °C (max)       |
|   | Output Impedance                                       | $-1 \ \mu A \le I_L \le +40 \ \mu A$  |                        | 1500                             | 1500                             | Ω (max)        |
|   | Line Regulation  | $+3.0V \le V^{+} \le +10V$ ,<br>$+25 \text{ °C} \le T_{A} \le +85 \text{ °C}$ |                        | -0.72/+0.3<br>6                  | -0.72/+0.3<br>6                  | mV/V (max)     |
|   |  | $+3.0V \le V^+ \le +10V$ ,<br>$-40 \text{ °C} \le T_A < 25 \text{ °C}$        |                        | -1.14/+0.6<br>1                  | -1.14/+0.6<br>1                  | mV/V (max)     |
|   |  | $+2.7V \le V^+ \le +3.3V$   |                        | ±2.3                             | ±2.3                             | mV (max)       |
| $\ensuremath{V_{T1}}$ and $\ensuremath{V_{T2}}$ | Analog Inputs  |   |                        |                                  |                                  |                |
| I <sub>BIAS</sub>                               | Analog Input Bias Current                              |   | 150                    | 300                              | 300                              | nA (max)       |
| $V_{IN}$  | Analog Input Voltage Range                             |   | V <sup>+</sup> - 1     |                                  |                                  | V              |
|   |  |   | GND                    |                                  |                                  | V              |
| V <sub>OS</sub>                                 | Comparator Offset                                      |   | 2                      | 8                                | 8                                | mV (max)       |
| V <sub>REF</sub> Output                         |  |   |                        |                                  |                                  |                |
| $V_{REF}$                                       | V <sub>REF</sub> Nominal                               |   | 1.250V                 |                                  |                                  | V              |
|   | V <sub>REF</sub> Error                                 |   |                        | ±1                               | ±1                               | % (max)        |
|   |  |   |                        | ±12.5                            | ±12.5                            | mV (max)       |
| $\Delta V_{REF}/\Delta V^{+}$                   | Line Regulation  | $+3.0V \le V^+ \le +10V$  | 0.13                   | 0.25                             | 0.25                             | mV/V (max)     |
|   |  | $+2.7V \le V^+ \le +3.3V$   | 0.15                   | 1.1                              | 1.1                              | mV (max)       |
| $\Delta V_{REF}/\Delta I_{L}$                   | Load Regulation Sourcing                               | $+30 \ \mu A \le I_{L} \le +50 \ \mu A$                                       |                        | 0.15                             | 0.15                             | mV/μA (max)    |

Typicals are at  $T_J = T_A = 25^{\circ}\text{C}$  and represent most likely parametric norm. Limits are guaranteed to Tl's AOQL (Average Outgoing Quality Level).

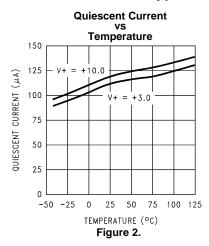
| Symbol                      | Parameter                          | Conditions                | Typical <sup>(1)</sup> | Limits <sup>(2)</sup> | Units (Limits) |
|-----------------------------|------------------------------------|---------------------------|------------------------|-----------------------|----------------|
| V <sup>+</sup> Power Supply |                                    |                           |                        |                       |                |
| I <sub>S</sub>              | Supply Current                     | V <sup>+</sup> = +10V     |                        | 230                   | μA (max)       |
|                             |                                    | $V^+ = +2.7V$             |                        | 230                   | μA (max)       |
| Digital Outputs             |                                    |                           |                        |                       |                |
| I <sub>OUT("1")</sub>       | Logical "1" Output Leakage Current | V <sup>+</sup> = +5.0V    |                        | 1                     | μA (max)       |
| V <sub>OUT("0")</sub>       | Logical "0" Output Voltage         | I <sub>OUT</sub> = +50 μA |                        | 0.4                   | V (max)        |

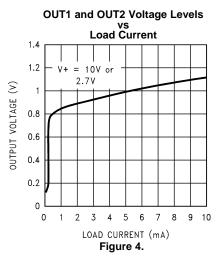
Typicals are at  $T_J$  =  $T_A$  = 25°C and represent most likely parametric norm. Limits are guaranteed to TI's AOQL (Average Outgoing Quality Level).

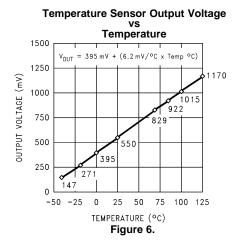
Product Folder Links: LM56

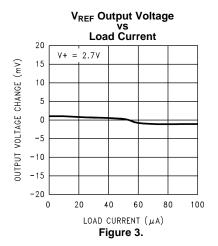


## **Typical Performance Characteristics**









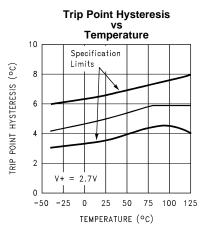
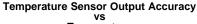
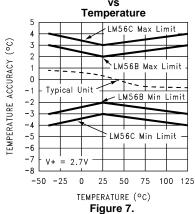


Figure 5.

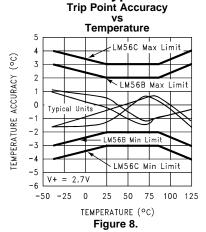




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## **Typical Performance Characteristics (continued)**



# Temperature 200 175 (V+ = 2.7V) 150 150 125 100 75 50 25

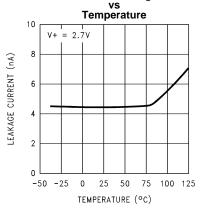
0

-50 -25

0 25

**Comparator Bias Current** 

#### **OUT1 and OUT2 Leakage Current**



V<sub>TEMP</sub> Output Line Regulation

TEMPERATURE (°C)
Figure 9.

50 75

100 125

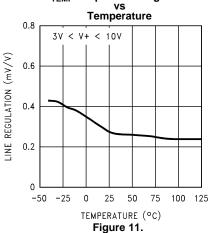
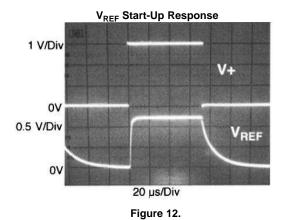


Figure 10.



1 V/Div 0V 0.5 V/Div 0V

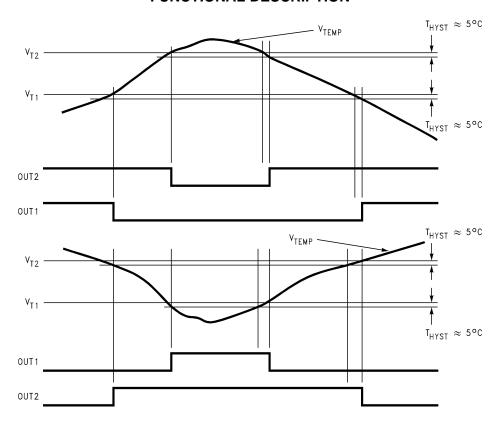
**V<sub>TEMP</sub> Start-Up Response** 

Figure 13.

20 µs/Div



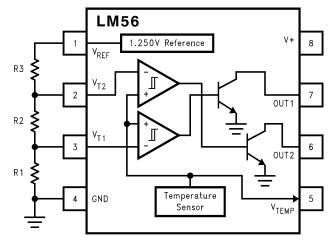
## **FUNCTIONAL DESCRIPTION**



### **Pin Functions**

| V <sup>+</sup>  | This is the positive supply voltage pin. This pin should be bypassed with a 0.1 µF capacitor to ground.  |
|-----------------|--|
| GND             | This is the ground pin.  |
| $V_{REF}$       | This is the 1.250V bandgap voltage reference output pin. In order to maintain trip point accuracy this pin should source a 50 $\mu$ A load.  |
| $V_{TEMP}$      | This is the temperature sensor output pin.   |
| OUT1            | This is an open collector digital output. OUT1 is active LOW. It goes LOW when the temperature is greater than $T_1$ and goes HIGH when the temperature drops below $T_1$ – 5°C. This output is not intended to directly drive a fan motor.                |
| OUT2            | This is an open collector digital output. OUT2 is active LOW. It goes LOW when the temperature is greater than the $T_2$ set point and goes HIGH when the temperature is less than $T_2$ – 5°C. This output is not intended to directly drive a fan motor. |
| V <sub>T1</sub> | This is the input pin for the temperature trip point voltage for OUT1.   |
| V <sub>T2</sub> | This is the input pin for the low temperature trip point voltage for OUT2.   |





 $\begin{array}{l} V_{T1} = 1.250V~x~(R1)/(R1+R2+R3) \\ V_{T2} = 1.250V~x~(R1+R2)/(R1+R2+R3) \\ where: \\ (R1+R2+R3) = 27~k\Omega~and \\ V_{T1~or~T2} = [6.20~mV/^{\circ}C~x~T] + 395~mV~therefore: \\ R1 = V_{T1}/(1.25V)~x~27~k\Omega \\ R2 = (V_{T2}/(1.25V)~x~27~k)\Omega - R1 \\ R3 = 27~k\Omega - R1 - R2 \end{array}$ 

## **Application Hints**

#### LM56 TRIP POINT ACCURACY SPECIFICATION

For simplicity the following is an analysis of the trip point accuracy using the single output configuration shown in Figure 14 with a set point of 82°C.

Trip Point Error Voltage =  $V_{TPE}$ ,

Comparator Offset Error for V<sub>T1E</sub>

Temperature Sensor Error =  $V_{TSE}$ 

Reference Output Error =  $V_{RE}$ 

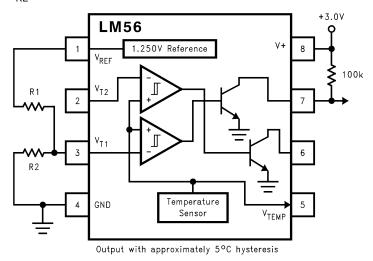


Figure 14. Single Output Configuration



1. 
$$V_{TPE} = \pm V_{T1E} - V_{TSE} + V_{RE}$$

Where

2.  $V_{T1E} = \pm 8 \text{ mV (max)}$ 

3. 
$$V_{TSF} = (6.20 \text{ mV/°C}) \text{ x } (\pm 3^{\circ}\text{C}) = \pm 18.6 \text{ mV}$$

4. 
$$V_{RF} = 1.250V \times (\pm 0.01) R2/(R1 + R2)$$

Using Equations from Figure 1.

$$V_{T1}$$
= 1.25V x R2/(R1 + R2) = 6.20 mV/°C)(82°C) + 395 mV

Solving for R2/(R1 + R2) = 0.7227

then,

5. 
$$V_{RE} = 1.250 \text{V x } (\pm 0.01) \text{ R2/(R1 + R2)} = (0.0125) \text{ x } (0.7227) = \pm 9.03 \text{ mV}$$

The individual errors do not add algebraically because, the odds of all the errors being at their extremes are rare. This is proven by the fact the specification for the trip point accuracy stated in the LM56 Electrical Characteristics for the temperature range of -40°C to +125°C, for example, is specified at ±3°C for the LM56BIM. Note this trip point error specification does not include any error introduced by the tolerance of the actual resistors used, nor any error introduced by power supply variation.

If the resistors have a  $\pm 0.5\%$  tolerance, an additional error of  $\pm 0.4$ °C will be introduced. This error will increase to  $\pm 0.8$ °C when both external resistors have a  $\pm 1\%$  tolerance.

#### **BIAS CURRENT EFFECT ON TRIP POINT ACCURACY**

Bias current for the comparator inputs is 300 nA (max) each, over the specified temperature range and will not introduce considerable error if the sum of the resistor values are kept to about 27 k $\Omega$  as shown in the typical application of Figure 1. This bias current of one comparator input will not flow if the temperature is well below the trip point level. As the temperature approaches trip point level the bias current will start to flow into the resistor network. When the temperature sensor output is equal to the trip point level the bias current will be 150 nA (max). Once the temperature is well above the trip point level the bias current will be 300 nA (max). Therefore, the first trip point will be affected by 150 nA of bias current. The leakage current is very small when the comparator input transistor of the different pair is off (see Figure 15).

The effect of the bias current on the first trip point can be defined by the following equations:

$$K1 = \frac{R1}{R1 + R2 + R3}$$

$$V_{T1} = K1 \times V_{REF} + K1 \times (R2 + R3) \times \frac{I_B}{2}$$
(1)

where  $I_B = 300$  nA (the maximum specified error).

The effect of the bias current on the second trip point can be defined by the following equations:

$$K2 = \frac{R1 + R2}{R1 + R2 + R3}$$

$$V_{T2} = K2 \times V_{REF} + \left(K1 + \frac{K2}{2}\right) \times R3 \times I_{B}$$
(2)

where  $I_B = 300$  nA (the maximum specified error).

The closer the two trip points are to each other the more significant the error is. Worst case would be when  $V_{T1} = V_{REF}/2$ .



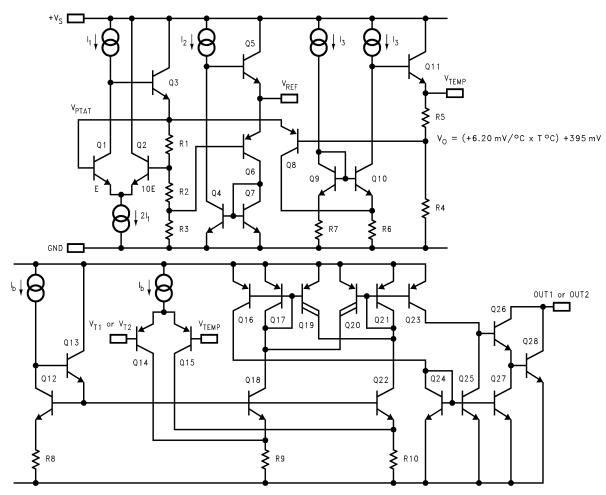


Figure 15. Simplified Schematic

#### **MOUNTING CONSIDERATIONS**

The majority of the temperature that the LM56 is measuring is the temperature of its leads. Therefore, when the LM56 is placed on a printed circuit board, it is not sensing the temperature of the ambient air. It is actually sensing the temperature difference of the air and the lands and printed circuit board that the leads are attached to. The most accurate temperature sensing is obtained when the ambient temperature is equivalent to the LM56's lead temperature.

As with any IC, the LM56 and accompanying wiring and circuits must be kept insulated and dry, to avoid leakage and corrosion. This is especially true if the circuit operates at cold temperatures where condensation can occur. Printed-circuit coatings are often used to ensure that moisture cannot corrode the LM56 or its connections.



#### **VREE AND VIEWS CAPACITIVE LOADING**

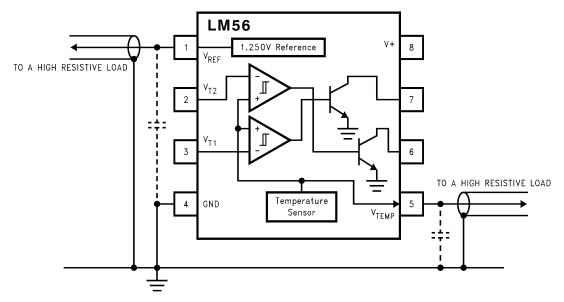


Figure 16. Loading of  $V_{REF}$  and  $V_{TEMP}$ 

The LM56  $V_{REF}$  and  $V_{TEMP}$  outputs handle capacitive loading well. Without any special precautions, these outputs can drive any capacitive load as shown in *Figure 16*.

#### **NOISY ENVIRONMENTS**

Over the specified temperature range the LM56  $V_{TEMP}$  output has a maximum output impedance of 1500 $\Omega$ . In an extremely noisy environment it may be necessary to add some filtering to minimize noise pickup. It is recommended that 0.1  $\mu$ F be added from  $V^+$  to GND to bypass the power supply voltage, as shown in Figure 16. In a noisy environment it may be necessary to add a capacitor from the  $V_{TEMP}$  output to ground. A 1  $\mu$ F output capacitor with the 1500 $\Omega$  output impedance will form a 106 Hz lowpass filter. Since the thermal time constant of the  $V_{TEMP}$  output is much slower than the 9.4 ms time constant formed by the RC, the overall response time of the  $V_{TEMP}$  output will not be significantly affected. For much larger capacitors this additional time lag will increase the overall response time of the LM56.

#### **APPLICATIONS CIRCUITS**

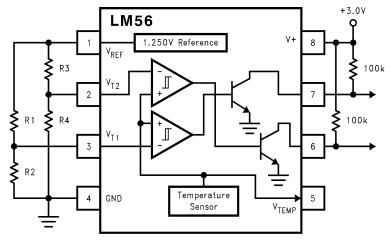


Figure 17. Reducing Errors Caused by Bias Current

Product Folder Links: LM56



The circuit shown in Figure 17 will reduce the effective bias current error for  $V_{T2}$  as discussed in Section 3.0 to be equivalent to the error term of  $V_{T1}$ . For this circuit the effect of the bias current on the first trip point can be defined by the following equations:

$$K1 = \frac{R2}{R1 + R2}$$

$$V_{T1} = K1 \times V_{REF} + K1 \times (R1) \times \frac{I_B}{2}$$
(3)

where  $I_B = 300$  nA (the maximum specified error).

Similarly, bias current affect on  $V_{T2}$  can be defined by:

$$K2 = \frac{R4}{R3 + R4}$$

$$V_{T1} = K2 \times V_{REF} + K1 \times (R3) \times \frac{I_B}{2}$$
(4)

where  $I_B = 300$  nA (the maximum specified error).

The current shown in Figure 18 is a simple overtemperature detector for power devices. In this example, an audio power amplifier IC is bolted to a heat sink and an LM56 Celsius temperature sensor is mounted on a PC board that is bolted to the heat sink near the power amplifier. To ensure that the sensing element is at the same temperature as the heat sink, the sensor's leads are mounted to pads that have feed throughs to the back side of the PC board. Since the LM56 is sensing the temperature of the actual PC board the back side of the PC board also has large ground plane to help conduct the heat to the device. The comparator's output goes low if the heat sink temperature rises above a threshold set by R1, R2, and the voltage reference. This fault detection output from the comparator now can be used to turn on a cooling fan. The circuit as shown in design to turn the fan on when heat sink temperature exceeds about 80°C, and to turn the fan off when the heat sink temperature falls below approximately 75°C.

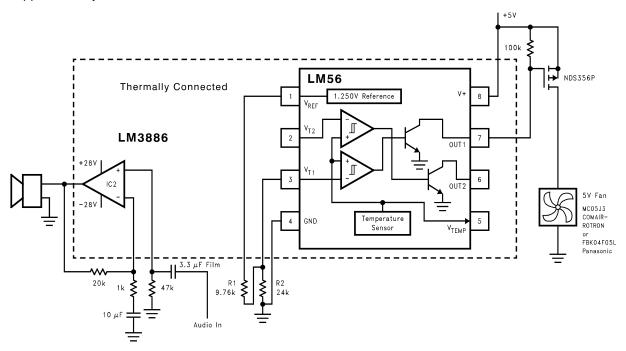


Figure 18. Audio Power Amplifier Overtemperature Detector



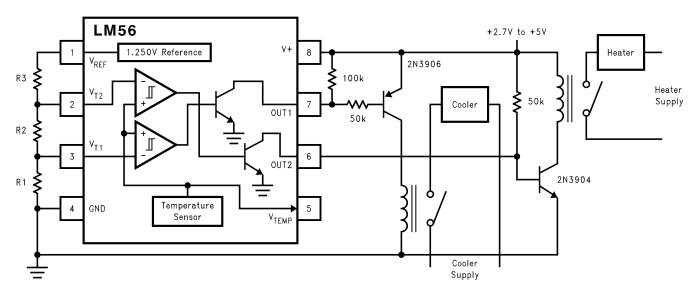


Figure 19. Simple Thermostat



## **REVISION HISTORY**

| Changes from Revision F (February 2013) to Revision G |  |    |  |  |  |  |  |
|---|--|----|--|--|--|--|--|
| •   | Changed layout of National Data Sheet to TI format | 13 |  |  |  |  |  |





12-Jul-2014

#### **PACKAGING INFORMATION**

| Orderable Device | Status | Package Type | Package<br>Drawing | Pins | Package<br>Qty | Eco Plan                   | Lead/Ball Finish (6) | MSL Peak Temp      | Op Temp (°C) | Device Marking (4/5) | Samples |
|------------------|--------|--------------|--------------------|------|----------------|----------------------------|----------------------|--------------------|--------------|----------------------|---------|
| LM56BIM          | NRND   | SOIC         | D                  | 8    | 95             | TBD                        | Call TI              | Call TI            | -40 to 125   | LM56<br>BIM          |         |
| LM56BIM/NOPB     | ACTIVE | SOIC         | D                  | 8    | 95             | Green (RoHS<br>& no Sb/Br) | CU SN                | Level-1-260C-UNLIM | -40 to 125   | LM56<br>BIM          | Sample  |
| LM56BIMM         | NRND   | VSSOP        | DGK                | 8    | 1000           | TBD                        | Call TI              | Call TI            | -40 to 125   | T02B                 |         |
| LM56BIMM/NOPB    | ACTIVE | VSSOP        | DGK                | 8    | 1000           | Green (RoHS<br>& no Sb/Br) | CU SN                | Level-1-260C-UNLIM | -40 to 125   | T02B                 | Sample  |
| LM56BIMMX/NOPB   | ACTIVE | VSSOP        | DGK                | 8    | 3500           | Green (RoHS<br>& no Sb/Br) | CU SN                | Level-1-260C-UNLIM | -40 to 125   | T02B                 | Sample  |
| LM56BIMX         | NRND   | SOIC         | D                  | 8    | 2500           | TBD                        | Call TI              | Call TI            | -40 to 125   | LM56<br>BIM          |         |
| LM56BIMX/NOPB    | ACTIVE | SOIC         | D                  | 8    | 2500           | Green (RoHS<br>& no Sb/Br) | CU SN                | Level-1-260C-UNLIM | -40 to 125   | LM56<br>BIM          | Sample  |
| LM56CIM          | NRND   | SOIC         | D                  | 8    | 95             | TBD                        | Call TI              | Call TI            | -40 to 125   | LM56<br>CIM          |         |
| LM56CIM/NOPB     | ACTIVE | SOIC         | D                  | 8    | 95             | Green (RoHS<br>& no Sb/Br) | CU SN                | Level-1-260C-UNLIM | -40 to 125   | LM56<br>CIM          | Sample  |
| LM56CIMM/NOPB    | ACTIVE | VSSOP        | DGK                | 8    | 1000           | Green (RoHS<br>& no Sb/Br) | CU SN                | Level-1-260C-UNLIM | -40 to 125   | T02C                 | Sample  |
| LM56CIMMX/NOPB   | ACTIVE | VSSOP        | DGK                | 8    | 3500           | Green (RoHS<br>& no Sb/Br) | CU SN                | Level-1-260C-UNLIM | -40 to 125   | T02C                 | Sample  |
| LM56CIMX         | NRND   | SOIC         | D                  | 8    | 2500           | TBD                        | Call TI              | Call TI            | -40 to 125   | LM56<br>CIM          |         |
| LM56CIMX/NOPB    | ACTIVE | SOIC         | D                  | 8    | 2500           | Green (RoHS<br>& no Sb/Br) | CU SN                | Level-1-260C-UNLIM | -40 to 125   | LM56<br>CIM          | Sample  |

<sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

**LIFEBUY:** TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

**PREVIEW:** Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



## PACKAGE OPTION ADDENDUM

12-Jul-2014

TBD: The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes. **Pb-Free** (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

- (3) MSL, Peak Temp. The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.
- (4) There may be additional marking, which relates to the logo, the lot trace code information, or the environmental category on the device.
- (5) Multiple Device Markings will be inside parentheses. Only one Device Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Device Marking for that device.
- (6) Lead/Ball Finish Orderable Devices may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead/Ball Finish values may wrap to two lines if the finish value exceeds the maximum column width.

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## PACKAGE MATERIALS INFORMATION

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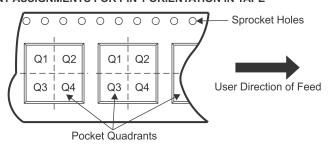
## TAPE AND REEL INFORMATION





|    | Dimension designed to accommodate the component width     |
|----|---|
| B0 | Dimension designed to accommodate the component length    |
| K0 | Dimension designed to accommodate the component thickness |
| W  | Overall width of the carrier tape                         |
| P1 | Pitch between successive cavity centers                   |

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

| Device         | Package<br>Type | Package<br>Drawing |   | SPQ  | Reel<br>Diameter<br>(mm) | Reel<br>Width<br>W1 (mm) | A0<br>(mm) | B0<br>(mm) | K0<br>(mm) | P1<br>(mm) | W<br>(mm) | Pin1<br>Quadrant |
|----------------|-----------------|--------------------|---|------|--------------------------|--------------------------|------------|------------|------------|------------|-----------|------------------|
| LM56BIMM       | VSSOP           | DGK                | 8 | 1000 | 178.0                    | 12.4                     | 5.3        | 3.4        | 1.4        | 8.0        | 12.0      | Q1               |
| LM56BIMM/NOPB  | VSSOP           | DGK                | 8 | 1000 | 178.0                    | 12.4                     | 5.3        | 3.4        | 1.4        | 8.0        | 12.0      | Q1               |
| LM56BIMMX/NOPB | VSSOP           | DGK                | 8 | 3500 | 330.0                    | 12.4                     | 5.3        | 3.4        | 1.4        | 8.0        | 12.0      | Q1               |
| LM56BIMX       | SOIC            | D                  | 8 | 2500 | 330.0                    | 12.4                     | 6.5        | 5.4        | 2.0        | 8.0        | 12.0      | Q1               |
| LM56BIMX/NOPB  | SOIC            | D                  | 8 | 2500 | 330.0                    | 12.4                     | 6.5        | 5.4        | 2.0        | 8.0        | 12.0      | Q1               |
| LM56CIMM/NOPB  | VSSOP           | DGK                | 8 | 1000 | 178.0                    | 12.4                     | 5.3        | 3.4        | 1.4        | 8.0        | 12.0      | Q1               |
| LM56CIMMX/NOPB | VSSOP           | DGK                | 8 | 3500 | 330.0                    | 12.4                     | 5.3        | 3.4        | 1.4        | 8.0        | 12.0      | Q1               |
| LM56CIMX       | SOIC            | D                  | 8 | 2500 | 330.0                    | 12.4                     | 6.5        | 5.4        | 2.0        | 8.0        | 12.0      | Q1               |
| LM56CIMX/NOPB  | SOIC            | D                  | 8 | 2500 | 330.0                    | 12.4                     | 6.5        | 5.4        | 2.0        | 8.0        | 12.0      | Q1               |

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\*All dimensions are nominal

| Device         | Package Type | Package Drawing | Pins | SPQ  | Length (mm) | Width (mm) | Height (mm) |
|----------------|--------------|-----------------|------|------|-------------|------------|-------------|
| LM56BIMM       | VSSOP        | DGK             | 8    | 1000 | 210.0       | 185.0      | 35.0        |
| LM56BIMM/NOPB  | VSSOP        | DGK             | 8    | 1000 | 210.0       | 185.0      | 35.0        |
| LM56BIMMX/NOPB | VSSOP        | DGK             | 8    | 3500 | 367.0       | 367.0      | 35.0        |
| LM56BIMX       | SOIC         | D               | 8    | 2500 | 367.0       | 367.0      | 35.0        |
| LM56BIMX/NOPB  | SOIC         | D               | 8    | 2500 | 367.0       | 367.0      | 35.0        |
| LM56CIMM/NOPB  | VSSOP        | DGK             | 8    | 1000 | 210.0       | 185.0      | 35.0        |
| LM56CIMMX/NOPB | VSSOP        | DGK             | 8    | 3500 | 367.0       | 367.0      | 35.0        |
| LM56CIMX       | SOIC         | D               | 8    | 2500 | 367.0       | 367.0      | 35.0        |
| LM56CIMX/NOPB  | SOIC         | D               | 8    | 2500 | 367.0       | 367.0      | 35.0        |

# DGK (S-PDSO-G8)

# PLASTIC SMALL-OUTLINE PACKAGE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 per end.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.50 per side.
- E. Falls within JEDEC MO-187 variation AA, except interlead flash.



## D (R-PDSO-G8)

## PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



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